# SN54LS446, SN54LS449, SN74LS446, SN74LS449 QUADRUPLE BUS TRANSCEIVERS WITH INDIVIDUAL DIRECTION CONTROLS

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- 3-State Outputs Drive Bus Lines Directly
- P-N-P Inputs Reduce DC Loading on Bus Line
- Hysteresis at Bus Inputs Improves Noise Margins
- Flow-Thru Data Pinout (B Bus Opposite A Bus)
- Choice of True ('LS449) and Inverting ('LS446)

#### description

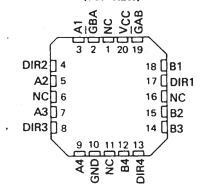
These quadruple bus transceivers are designed for data transmission from individual lines of the A bus to individual lines of the B bus or the reverse, depending on the logic levels at the direction-control pins DIR1 through DIR4. These direction controls (one for each channel) allow maximum flexibility in timing. The enable inputs  $\overline{G}BA$  and  $\overline{G}AB$  can be used to disable the A or B outputs respectively, or to disable both buses for effective isolation.

The SN54LS446 and SN54LS449 are characterized for operation over the full military temperature range of  $-55^{\circ}$ C to  $125^{\circ}$ C. The SN74LS446 and SN74LS449 are characterized for operation from  $0^{\circ}$ C to  $70^{\circ}$ C.

#### SN54LS446, SN54LS449 . . . J PACKAGE SN74LS446, SN74LS449 . . . D OR N PACKAGE (TOP VIEW)

GBA 1 16 VCC
A1 2 15 GAB
DIR2 3 14 B1
A2 4 13 DIR1
A3 5 12 B2
DIR3 6 11 B3
A4 7 10 DIR4
GND 8 9 R4

# SN54LS446, SN54LS449 . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

#### **FUNCTION TABLE**

ENABLE DI GBA GAB H H X L		DIRECTION	OPERATION	OPERATION		
		DIR	'LS446	'LS449		
		X	Isolation	Isolation A data to B Bus		
		Н	A data to B Bus			
L	×	L	B data to A Bus	B data to A Bus		
Х	Н	Н	Isolation	Isolation		
Н	×	L	Isolation	Isolation		

H = high level, L = low level, X = irrelevant

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

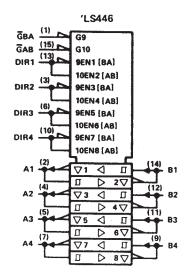
Supply voltage, VCC (see Note 1)	 7 V
Input voltage	 7 V
Off-state output voltage	 5 V
Operating free-air temperature range: SN54LS'	 5°C
SN74LS'	 o°c
Storage temperature range	 0°C

NOTE 1: Voltage values are with respect to the network ground terminal.

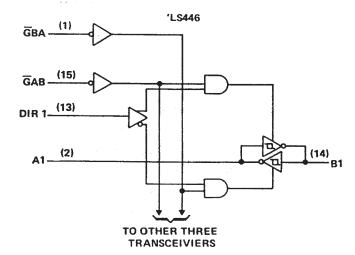
TEXAS INSTRUMENTS

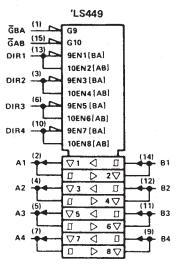
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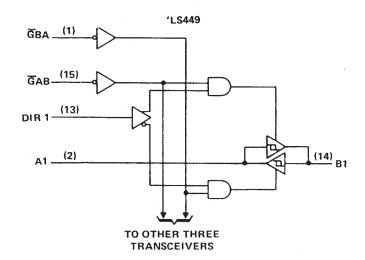
#### logic symbols†



#### logic diagrams (positive logic)

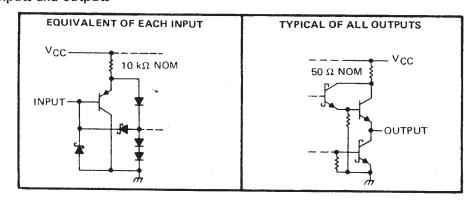






 $<sup>^\</sup>dagger$  These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for D, J, and N packages.

#### schematics of inputs and outputs





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### recommended operating conditions

PARAMETER	SN54LS446 SN74LS446 SN54LS449 SN74LS449							
	MIN	NOM	MAX	MIN	NOM	MAX	1	
Supply voltage, V <sub>CC</sub> (see Note 1)	4.5	5	5.5	4.75	5	5.25	V	
High-level output current, IOH			-12	1		-15	mA	
Low-level output current, IOL			12			24	mA	
Operating free-air temperature, TA	-55		125	0		70	°c	

NOTE 1: Voltage values are with respect to network ground terminal

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS†		1	154LS44 154LS44		S	UNIT			
					MIN	TYP‡	MAX	MIN	MIN TYP‡ MAX		
VIH	High-level input voltage				2			2			V
VIL	Low-level input voltage						0.6			0.7	V
VIK	Input clamp voltage		V <sub>CC</sub> = MIN,	I <sub>I</sub> = -18 mA			-1.5			-1.5	V
	Hysteresis ( $V_{T+} - V_{T-}$ ),	A or B input	VCC = MIN		0.1	0.4		0.2	0.4		V
Vон	High-level output voltage		V <sub>CC</sub> = MIN, V <sub>IH</sub> = 2 V,	I <sub>OH</sub> = -3 mA	2.4	3.4		2.4	3.4		v
			VIL = VIL max	I <sub>OH</sub> = MAX	2			2			
Vol	Low-level output voltage		V <sub>CC</sub> = MIN, V <sub>IH</sub> = 2 V,	I <sub>OL</sub> = 12 mA		0.25	0.4		0.25	0.4	v
			VIL = VIL max	IOL = 24 mA					0.35	0.5	
lozh	Off-state output current,		V <sub>CC</sub> = MAX,	$\overline{G}$ at 2 V,		-					1
10ZH	high-level voltage applied		V <sub>O</sub> = 2.7 V				20			20	μΑ
lozu	Off-state output current,		V <sub>CC</sub> = MAX,	Gat 2 V,	<u> </u>					-	
102L	low-level voltage applied		V <sub>O</sub> = 0.4 V			- 0.4				- 0.4	mA
l <sub>1</sub>	Input current at	A or B	1/ MAAY	V <sub>1</sub> = 5.5 V			0.1			0.1	<u> </u>
'1	maximum input voltage	GAB or GBA	V <sub>CC</sub> = MAX,	V <sub>1</sub> = 7 V			0.1	<b>†</b>		0.1	mA
ЧН	High-level input current		VCC = MAX,	V <sub>1</sub> = 2.7 V			20			20	μА
HL	Low-level input current	-	V <sub>CC</sub> = MAX,	V <sub>1</sub> = 0.4 V			-0.4			-0.4	mA
los	Short-circuit output curre	nt§	V <sub>CC</sub> = MAX		-40		-225	-40	.,	-225	mA
	'LS446 Total supply current 'LS449			Outputs high		35	56		35	56	<b>†</b>
		'LS446		Outputs low		39	63	T	39	63	1
<sup>1</sup> cc		VCC	V <sub>CC</sub> = MAX,	Outputs at Hi-Z		42	68		42	68	1 .
			Outputs open	Outputs high		42	68		42	68	mΑ
		'LS449	·	Outputs low	Ī	47	75		47	75	1
				Outputs at Hi-Z		50	80		50	80	1

<sup>†</sup> For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.



 $<sup>^{\</sup>ddagger}$  All typical values are at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25 °C.

<sup>&</sup>lt;sup>5</sup> Not more than one output should be shorted at a time, and duration of the short-circuit should not exceed one second.

## SN54LS446, SN54LS449, SN74LS446, SN74LS449 QUADRUPLE BUS TRANSCEIVERS WITH INDIVIDUAL DIRECTION CONTROLS

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# switching characteristics at VCC = 5 V, $T_A$ = 25°C

	PARAMETER	1.	TO (OUTPUT)	TEST CONDITIONS	'LS446			'L\$449			
			10011017		MIN	TYP	MAX	MIN	TYP	MAX	UNIT
<sup>t</sup> PLH	Propagation delay time,	Α	В			8	13		10	15	
TLIT	low-to-high-level output	В	Α			8	13		10	15	ns
tou	Propagation delay time,	Α	В	CL = 45 pF,		7	12		11	17	-
†PHL	high-to-low-level output	В	Α	_		7	12		11	17	ns
<sup>t</sup> PZL	Output enable time to low level	ĞВА	Α	R <sub>L</sub> =667Ω,		24	40		21	35	<del> </del>
		GAB	В			24	40		21	35	ns
*	Output enable time to high level	ĞВА	Α	See Note 2		15	25		18	30	<del>                                     </del>
ФZH		ĞАВ	В			15	25		18	30	ns
	Output disable time from low level	Ğва	A	Cլ=5pF,		14	25		14	25	
ΨLZ		ĞAB	В		Cլ=5pF,		14	25		14	25
tpHZ (	Output disable time from high level	GP.A	A	$R_L = 667 \Omega$ ,		10	15				
		GAB	В	See Note 2		10	15		10	15 15	ns

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.



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